



#### 74LVC1G00Q

#### SINGLE 2 INPUT POSITIVE NAND GATE

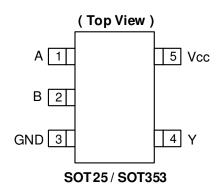
#### Description

The 74LVC1G00Q is an automotive compliant, single, 2-input positive NAND gate with a standard push-pull output. The device is designed for operation with a power supply range of 1.65V to 5.5V. The inputs are tolerant to 5.5V allowing this device to be used in a mixed-voltage environment. The device is fully specified for partial power-down applications using IOFF. The IOFF circuitry disables the output preventing damaging current backflow when the device is powered down.

The gate performs the positive Boolean function:

$$Y = \overline{A \bullet B} \text{ or } Y = \overline{A} + \overline{B}$$

#### **Pin Assignments**



### Features

- Grade 1 Ambient Temperature Operation: -40°C to +125°C
- Wide Supply Voltage Range from 1.65V to 5.5V
- ±24mA Output Drive at 3.3V
- CMOS Low Power Consumption
- IOFF Supports Partial-Power-Down Mode Operation
- Inputs Accept up to 5.5V
- ESD Protection Tested per AEC-Q100
- Exceeds 2000V Human Body Model (AEC-Q100-002)
- Exceeds 1000V Charged Device Model (AEC-Q100-011)
- Latch-Up Exceeds 100mA (AEC-Q100-004)
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The 74LVC1G00Q is suitable for automotive applications requiring specific change control; this part is AEC-Q100 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/guality/product-definitions/

- Notes:
- No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
  See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

# Applications

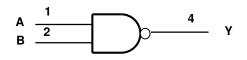
- Voltage Level Shifting
- General Purpose Logic
- Power-Down Signal Isolation
- Wide Array of Products such as:
  - Automotive Applications within Grade 1 Temperature Range
  - Industrial Computing/Controls/Automation
  - High-Reliability Networking/Communications
  - Industrial/Agricultural Equipment



### **Pin Descriptions**

Pin Name	Description
A	Data Input
В	Data Input
GND	Ground
Y	Data Output
V <sub>CC</sub>	Supply Voltage

### Logic Diagram



### **Function Table**

Inp	Output	
Α	В	Y
Н	Н	L
L	Х	н
Х	L	Н

### Absolute Maximum Ratings (Notes 4 & 5)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
Vcc	Supply Voltage Range	-0.5 to 6.5	V
VI	Input Voltage Range	-0.5 to 6.5	V
Vo	Voltage Applied to Output in High Impedance or IOFF State	-0.5 to 6.5	V
Vo	Voltage Applied to Output in High or Low State	-0.5 to Vcc +0.5	V
Ік	Input Clamp Current VI < 0	-50	mA
Іок	Output Clamp Current	-50	mA
lo	Continuous Output Current	±50	mA
Icc, Ignd	Continuous Current Through Vcc or GND	±100	mA
TJ	Operating Junction Temperature	-40 to +150	°C
Tstg	Storage Temperature	-65 to +150	°C

Notes: 4. Stresses beyond the absolute maximum can result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

Forcing the maximum allowed voltage could cause a condition exceeding the maximum current or conversely forcing the maximum current could cause a condition exceeding the maximum voltage. The ratings of both current and voltage must be maintained within the controlled range.



## Recommended Operating Conditions (Note 6)

Symbol	Pa	rameter	Min	Max	Unit	
N/		Operating	1.65	5.5	V	
Vcc	Operating Voltage	Data Retention Only	1.5	—	V	
		Vcc = 1.65V to 1.95V	$0.65 \times V_{CC}$	_		
Vін	High-Level Input Voltage	V <sub>CC</sub> = 2.3V to 2.7V	1.7	—	V	
VIH	High-Level liput voltage	$V_{CC} = 3V$ to 3.6V	2	—	v	
		$V_{CC} = 4.5V$ to 5.5V	$0.7  imes V_{CC}$	—		
		V <sub>CC</sub> = 1.65V to 1.95V	—	$0.35 \times V_{CC}$		
.,	Level and here the sec	V <sub>CC</sub> = 2.3V to 2.7V	—	0.7		
VIL	Low-Level Input Voltage	V <sub>CC</sub> = 3V to 3.6V	—	0.8	V	
		V <sub>CC</sub> = 4.5V to 5.5V	_	$0.3  imes V_{CC}$		
VI	Input Voltage		0	5.5	V	
Vo	Output Voltage		0	Vcc	V	
		V <sub>CC</sub> = 1.65V	_	-4		
		V <sub>CC</sub> = 2.3V	_	-8		
1	High-Level Output Current	V <sub>CC</sub> = 2.7V	_	-12	mA	
lон			_	-16	IIIA	
		$V_{CC} = 3V$	—	-24		
		$V_{CC} = 4.5V$	—	-32		
		$V_{CC} = 1.65V$	—	4		
		$V_{CC} = 2.3 V$	—	8		
IOL	Low-Level Output Current	Vcc = 2.7V	—	12	mA	
IOL		$V_{CC} = 3V$	—	16	IIIA	
		VCC = 3V		24		
		$V_{CC} = 4.5V$	—	32		
		$V_{CC} = 1.8V \pm 0.15V, 2.5V \pm 0.2V$		20		
Δt/ΔV	Input Transition Rise or Fall Rate	$V_{CC} = 3.3V \pm 0.3V$	—	10	ns/V	
		$V_{CC} = 5V \pm 0.5V$	—	5		
TA	Operating Free-Air Temperature	—	-40	+125	°C	

Note: 6. Unused inputs should be held at V<sub>CC</sub> or Ground.



#### **Electrical Characteristics** (All typical values are at $V_{CC} = 3.3V$ , $T_A = +25^{\circ}C$ )

Cumphed	Devenenter	Test Os	nditiono		-40°	C to +125	°C	l lucit	
Symbol	Parameter	Test Conditions		Vcc	Min	Тур	Max	Unit	
			Іон = -100μА	1.65V to 5.5V	Vcc-0.1	_			
			lон = -4mA	1.65V	0.95	_			
Vон	High Level Output Voltage	VI = VIH or VIL	Iон = -8mA	2.3V	1.7			v	
VOH	riigh Level Output Voltage		Iон = -12mA	2.7V	1.9	—		v	
			Iон = -24mA	3V	2.0	_			
			I <sub>OH</sub> = -32mA	4.5V	3.4	-			
	Vo∟ Low Level Output Voltage			I <sub>OL</sub> = 100μA	1.65V to 5.5V	—	_	0.10	
		ow Level Output Voltage $V_I = V_{IH}$ or $V_{IL}$	I <sub>OL</sub> = 4mA	1.65V	—	_	0.70	v	
.,			I <sub>OL</sub> = 8mA	2.3V	—	_	0.45		
VOL			$I_{OL} = 12mA$	2.7V	—	_	0.60		
			$I_{OL} = 24mA$	3V	—	_	0.80		
			I <sub>OL</sub> = 32mA	4.5V	_		0.80		
lı –	Input Current	VI = 5.5V or GN	ID	0 to 5.5V	—	±0.1	±1	μA	
IOFF	Power Down Leakage Current	$V_{I} \text{ or } V_{O} = 5.5 V$		0V	—	_	±2	μA	
lcc	Supply Current	V <sub>I</sub> = 5.5V or GND I <sub>O</sub> = 0		5.5V	—	0.1	4	μA	
Δlcc	Additional Supply Current	One input at $V_{CC} - 0.6V$ Other inputs at $V_{CC}$ or GND		3V to 5.5V	_	—	500	μA	
Cı	Input Capacitance	$V_I = GND$ to $V_C$	c	3.3V	—	5.0		pF	

### Package Characteristics

Symbol	Parameter	Package	Test Conditions	Min	Тур	Max	Unit
0	Thermal Resistance	SOT25	Niete 7		184	_	0 <b>0</b> AN
θ <sub>JA</sub> Junction-to-Ambient	SOT353	Note 7	_	385	_	°C/W	
0.5	Thermal Resistance	SOT25	Niete 7		62	_	00444
θ <sub>JC</sub> Junction-to-C	Junction-to-Case	SOT353	Note 7		164	_	°C/W

Note: 7. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

### **Switching Characteristics**

Figure 1 Typical Values at  $T_A = +25^{\circ}C$  and nominal voltages 1.8V, 2.5V, 2.7V, 3.3V, and 5.0V.

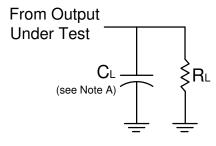
Parameter	From	То	Vcc	T <sub>A</sub> = -40°C to +125°C			Unit
Falametei	Input	Output	VCC	Min	Тур	Max	onit
	tPD A or B Y	1.8V ± 0.15V	1.0	3.3	10.5		
		Y	$2.5V \pm 0.2V$	0.5	2.2	7.0	
tpd			2.7V	0.5	2.6	7.5	ns
		$3.3V \pm 0.3V$	0.5	2.2	6.0		
		$5.0V \pm 0.5V$	0.5	1.8	5.5		

### **Operating Characteristics**

	Parameter	Test Conditions	Vcc = 1.8V Typ	Vcc = 2.5V Typ	Vcc = 3.3V Typ	Vcc = 5V Typ	Unit
Cpd	Power Dissipation Capacitance	f = 10MHz	15	16	16	16	pF



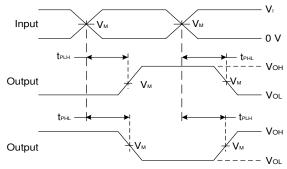
#### **Measurement Information**



Vcc	In	puts	VM	CL	RL	
VCC	Vi	tR/tF	۷M	OL .		
1.8V ± 0.15V	Vcc	≤2ns	Vcc/2	30pF	1kΩ	
2.5V ± 0.2V	Vcc	≤2ns	Vcc/2	30pF	500Ω	
2.7V	V <sub>CC</sub>	≤2.5ns	1.5V	50pF	500Ω	
3.3V ± 0.3V	3.0V	≤2.5ns	1.5V	50pF	500Ω	
5.0V ± 0.5V	Vcc	≤2.5ns	Vcc/2	50pF	500Ω	







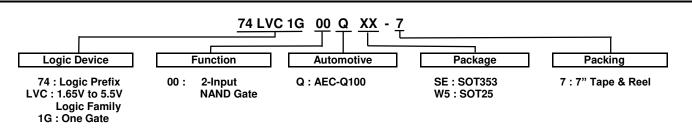
Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs

#### Figure 1. Load Circuit and Voltage Waveforms

- Notes: A. Includes test lead and test apparatus capacitance.
  - B. All pulses are supplied at pulse repetition rate  $\leq$  10MHz.
  - C. Inputs are measured separately one transition per measurement.
  - D.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{PD}$ .



#### Ordering Information (Note 8)



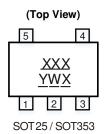
Part Number	Package	Package	Package	7" Tape	and Reel
Fait Nulliber	Code	(Notes 9 & 10)	Size	Quantity	Part Number Suffix
74LVC1G00QSE-7	SE	SOT353	2.0mm × 2.0mm × 1.1mm 0.65mm lead pitch	3000/Tape & Reel	-7
74LVC1G00QW5-7	W5	SOT25	3.0mm × 2.8mm × 1.2mm 0.95mm lead pitch	3000/Tape & Reel	-7

8. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Pad layout as shown in Diodes Incorporated's package outline PDFs, which can be found on our website at http://www.diodes.com/package-outlines.html.
 The taping orientation is located on our website at https://www.diodes.com/assets/Packaging-Support-Docs/ap02007.pdf.

### **Marking Information**

Notes:



XXX : Identification Code Y : Year 0~9 W : Week:A~Z 1~26 week a~z 27~52 week z represents week 52 and 53 X : A~Z: Internal Code

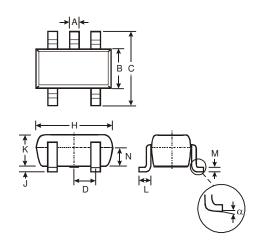
Part Number	Package	Identification Code
74LVC1G00QW5-7	SOT25	USQ
74LVC1G00QSE-7	SOT353	USQ



### **Package Outline Dimensions**

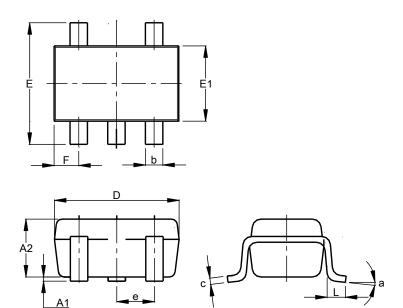
Please see http://www.diodes.com/package-outlines.html for the latest version.

(1) Package Type: SOT25



SOT25					
Dim	Min	Max	Тур		
Α	0.35	0.50	0.38		
В	1.50	1.70	1.60		
С	2.70	3.00	2.80		
D	-	-	0.95		
н	2.90	3.10	3.00		
J	0.013	0.10	0.05		
К	1.00	1.30	1.10		
L	0.35	0.55	0.40		
М	0.10	0.20	0.15		
Ν	0.70	0.80	0.75		
α	0°	8°	-		
All Dimensions in mm					

#### (2) Package Type: SOT353



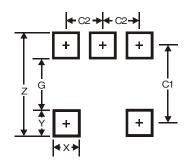
	SOT353				
Dim	Min	Max	Тур		
A1	0.00	0.10	0.05		
A2	0.90	1.00	0.95		
b	0.10	0.30	0.25		
С	0.10	0.22	0.11		
D	1.80	2.20	2.15		
Е	2.00	2.20	2.10		
E1	1.15	1.35	1.30		
е	0.650 BSC				
F	0.40	0.45	0.425		
L	0.25	0.40	0.30		
а	0°	8°			
All Dimensions in mm					



### **Suggested Pad Layout**

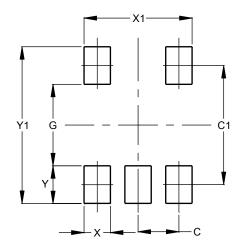
Please see http://www.diodes.com/package-outlines.html for the latest version.

(1) Package Type: SOT25



Dimensions	Value
Z	3.20
G	1.60
Х	0.55
Y	0.80
C1	2.40
C2	0.95

#### (2) Package Type: SOT353



Dimensions	Value (in mm)
С	0.650
C1	1.900
G	1.300
Х	0.420
X1	1.720
Y	0.600
Y1	2.500

#### **Mechanical Data**

#### SOT25

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208<sup>(3)</sup>
- Weight: 0.0158 grams (Approximate)

#### SOT353

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 3
- Weight: 0.0064 grams (Approximate)



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